Product data sheet

1. Product profile

1.1 General description

Ultrafast power diode in a SOD59 (2-lead TO-220AC) plastic package.

1.2 Features and benefits

- Fast switching
- High thermal cycling performance
- Low forward volt drop

- Low thermal resistance
- Soft recovery minimizes power-consuming oscillations

1.3 Applications

Discontinuous Current Mode (DCM)
 Power Factor Correction (PFC)

 Output rectifiers in high-frequency switched-mode power supplies

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	-	400	V
I _{F(AV)}	average forward current	square-wave pulse; $\delta = 0.5$; $T_{mb} \le 123$ °C; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	-	9	A
Static char	racteristics					
V_{F}	forward voltage	$I_F = 8 \text{ A}; T_j = 150 ^{\circ}\text{C}; \text{ see } \frac{\text{Figure 4}}{}$	-	0.9	1.03	V
Dynamic c	haracteristics					
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/s}$; $T_j = 25 \text{ °C}$; see Figure 7; see Figure 5	-	50	60	ns



Ultrafast power diode

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		v. 1.4
2	Α	anode	mb	K — A 001aaa020
mb	mb	mounting base; cathode	Ι Ο 1	
			0	
			1 2	
			SOD59 (TO-220AC)	

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BYV29-400	TO-220AC	plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Parameter	Conditions	Min	Max	Unit
repetitive peak reverse voltage		-	400	V
crest working reverse voltage		-	400	V
reverse voltage	DC	-	400	V
average forward current	square-wave pulse; $\delta = 0.5$; $T_{mb} \le 123$ °C; see Figure 1; see Figure 2	-	9	Α
repetitive peak forward current	square-wave pulse; $\delta = 0.5$; $t_p = 25 \mu s$; $T_{mb} \le 123 ^{\circ}C$	-	18	Α
non-repetitive peak forward	sine-wave pulse; $t_p = 10 \text{ ms}$; $T_{j(init)} = 25 \text{ °C}$	-	100	Α
current	sine-wave pulse; $t_p = 8.3 \text{ ms}$; $T_{j(init)} = 25 ^{\circ}\text{C}$	-	110	Α
storage temperature		-40	150	°C
junction temperature		-	150	°C
	repetitive peak reverse voltage crest working reverse voltage reverse voltage average forward current repetitive peak forward current non-repetitive peak forward current storage temperature	repetitive peak reverse voltage crest working reverse voltage policy preverse voltage policy peak forward current prepetitive peak forward current square-wave pulse; $\delta = 0.5$; $T_{mb} \le 123$ °C; see Figure 1; see Figure 2 pulse; $\delta = 0.5$;	repetitive peak reverse voltage - crest working reverse voltage - DC - average forward current square-wave pulse; $\delta = 0.5$; $T_{mb} \le 123$ °C; see Figure 1; see Figure 2 repetitive peak forward current square-wave pulse; $\delta = 0.5$; $t_p = 25 \mu s$; $t_{mb} \le 123$ °C non-repetitive peak forward sine-wave pulse; $t_p = 10 ms$; $t_{j(init)} = 25 c$ current storage temperature -40	repetitive peak reverse voltage - 400 crest working reverse voltage - 400 reverse voltage DC - 400 average forward current square-wave pulse; $\delta = 0.5$; $T_{mb} \le 123$ °C; - 9 repetitive peak forward current square-wave pulse; $\delta = 0.5$; $t_p = 25 \mu s$; - 18 $T_{mb} \le 123$ °C - 100 current sine-wave pulse; $t_p = 10 ms$; $T_{j(init)} = 25$ °C - 110 storage temperature -40 150

NXP Semiconductors BYV29-400

Ultrafast power diode

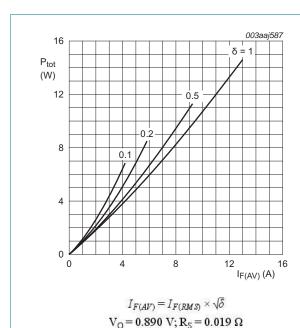


Fig 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

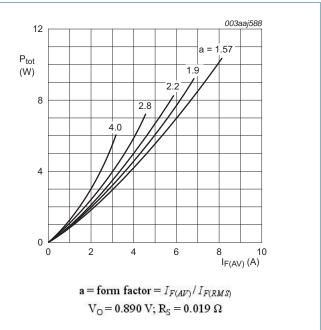


Fig 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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Ultrafast power diode

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	see Figure 3	-	-	2.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

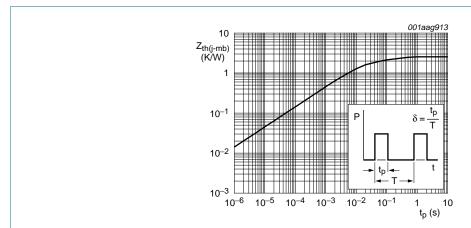
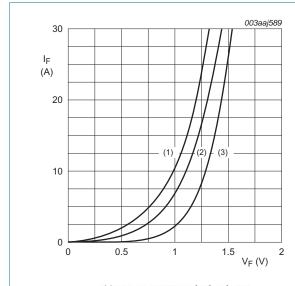


Fig 3. Transient thermal impedance from junction to mounting base as a function of pulse width

6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V_{F}	forward voltage	I _F = 8 A; T _j = 150 °C; see <u>Figure 4</u>	-	0.9	1.03	V
		I _F = 8 A; T _j = 25 °C; see <u>Figure 4</u>	-	1.05	1.25	V
		$I_F = 20 \text{ A}; T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure 4}}{}$	-	1.2	1.4	V
I _R	reverse current	$V_R = 400 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	2	50	μΑ
		V _R = 400 V; T _j = 100 °C	-	0.1	0.35	mΑ
Dynamic	characteristics					
Q _r	recovered charge	$I_F = 2 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 20 \text{ A/s}$; $T_j = 25 \text{ °C}$; see Figure 5; see Figure 6	-	40	60	nC
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/s}$; $T_j = 25 \text{ °C}$; see Figure 7; see Figure 5	-	50	60	ns
I _{RM}	peak reverse recovery current	$I_F = 10 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 50 \text{ A/s}$; $T_j = 100 \text{ °C}$; see Figure 8; see Figure 5	-	4	5.5	Α
V_{FRM}	forward recovery voltage	$I_F = 10 \text{ A}$; $dI_F/dt = 10 \text{ A/s}$; $T_j = 25 \text{ °C}$; see Figure 9	-	2.5	-	V



(1) $T_j = 150$ °C; typical values;

(2) $T_j = 150$ °C; maximum values;

(3) $T_j = 25$ °C; maximum values; $V_O = 0.890$ V; $R_S = 0.019$ Ω

Fig 4. Forward current as a function of forward voltage

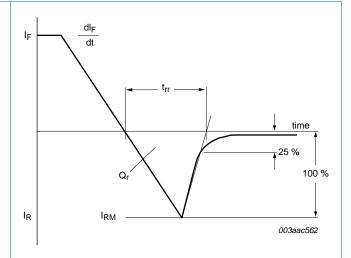
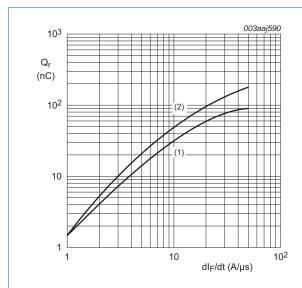


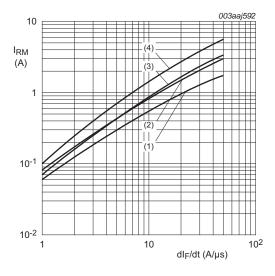
Fig 5. Reverse recovery definitions; ramp recovery



(1)
$$I_F = 2 A$$
; $T_j = 25 °C$;

(2)
$$I_F = 10 \text{ A}$$
; $T_j = 25 \text{ }^{\circ}\text{C}$





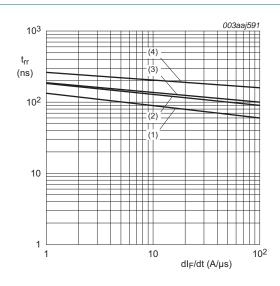
(1)
$$I_F = 1 A$$
; $T_i = 25 \, ^{\circ}\text{C}$;

(2)
$$I_F = 1 A$$
; $T_j = 100 °C$;

(3)
$$I_F = 10 A; T_j = 25 °C;$$

(4)
$$I_F = 10 A$$
; $T_j = 100 °C$

Fig 8. Peak reverse recovery current as a function of rate of change of forward current; maximum values



(1) $I_F = 1 A$; $T_j = 25 \, ^{\circ}C$;

(2)
$$I_F = 1 A$$
; $T_j = 100 °C$;

(3)
$$I_F = 10 \text{ A}; T_j = 25 \text{ °C};$$

(4)
$$I_F = 10 \text{ A}; T_j = 100 \text{ }^{\circ}\text{C}$$

Fig 7. Reverse recovery time as a function of rate of change of forward current; maximum values

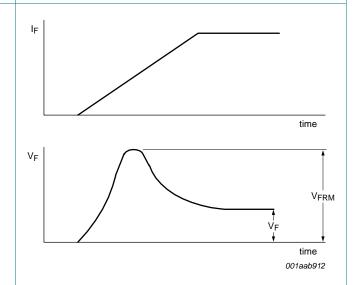


Fig 9. Forward recovery definitions

7. Package outline

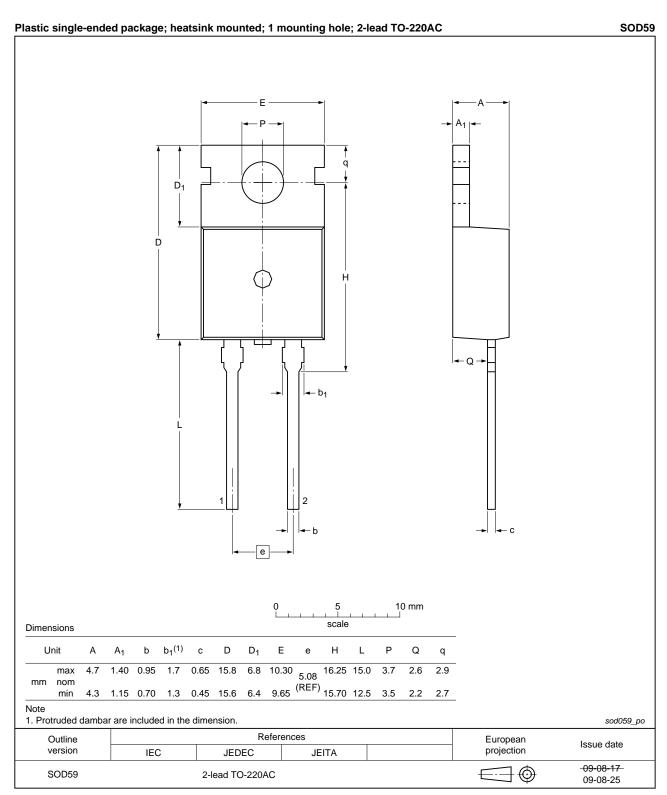


Fig 10. Package outline SOD59 (TO-220AC)

Ultrafast power diode

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BYV29-400 v.3	20120529	Product data sheet	-	BYV29_SERIES v.2	
Modifications:	Type number BYVVarious changes t	29-400 separated from da o content.	ata sheet BYV29_SERIE	S v.2.	
BYV29_SERIES v.2	19980901	Product specification	-	BYV29_SERIES v.1	

9. Legal information

9.1 Data sheet status

Document status[1] [2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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